NSN 5961-01-250-3395

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Ceramic
Overall Length:
0.758 inches
Terminal Length:
0.138 inches
Overall Height:
0.316 inches
Overall Width:
0.312 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Mo-036ac
Component Name And Quantity:
4 transistor
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case and electrostatic sensitive
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
-100.0 drain to source voltage all transistor
Current Rating Per Characteristic:
-3.00 amperes off-state current, peak all transistor
Power Rating Per Characteristic:
2.5 watts total device dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
14 pin
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0